

# SLDA-61S16-XX Series

## **Multielement Array**

### Features

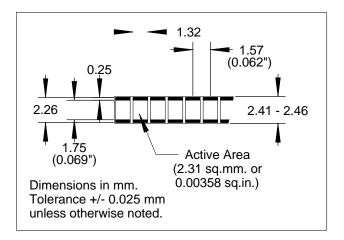
- Diodes spaced on 1.57 mm centers
- Contacts along both edges of the array
- Common cathode contact on the back
- Solderable anode contacts on top surface
- Up to 16 elements per monolithic array

#### Description

The Silonex SLDA-61S16-XX series of photodiode arrays are monolithic devices that can be used in precision position sensing applications. The array can be easily bonded with conductive epoxy to a ceramic or other substrate. The conductive epoxy provides the electrical connection to the common cathode contact.

#### **Absolute Maximum Ratings**

Storage Temperature	-40 to +125°C
Operating Temperature	-40 to +125°C
Soldering Temperature	260°C for 2 sec



To order this part the 'XX' refers to the number of elements in the array (from 02 to 16 elements).

#### **Electrical Characteristics** (per element, $T_A=25^{\circ}C$ unless otherwise noted)

Symbol	Parameter	MIN	TYP	MAX	UNITS	TEST CONDITIONS
I <sub>SC</sub>	Short Circuit Current	80	120		μΑ	$V_{R} = 0V, Ee = 25 \text{ mW/cm}^{2}$ (1)
V <sub>oc</sub>	Open Circuit Voltage		0.40		V	$Ee = 25 \text{ mW/cm}^2$ (1)
I <sub>D</sub>	Dark Current			3	μΑ	$Ee = 0, V_R = 1V$
$V_{BR}$	Breakdown Voltage	20			V	I <sub>R</sub> = 100 μA
TCI	Temp. Coef., I <sub>SC</sub>		+0.2		%/°C	(1)
CJ	Junction Capacitance		150		pF	$F = 1 Mhz, V_R = 0$
λ <sub>P</sub>	Maximum Sensitivity Wavelength		930		nm	
λ <sub>R</sub>	Sensitivity Spectral Range	400		1100	nm	

Specifications subject to change without notice.

Note: (1) Ee = light source @ 2854 °K

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